

NCP140

150 mA, Capacitor Free, Very Low Dropout CMOS Voltage Regulator

The NCP140 is a 150 mA very low dropout regulator which offers excellent voltage accuracy and clean output voltage for power sensitive application. The NCP140 is very suitable for battery powered application due to very low quiescent current and virtually zero current at disable mode. This device is stable with or without output capacitors and allows minimize footprint and BOM. The XDFN4 package is optimized for use in space constrained applications.

Features

- Stable Operation with or without Capacitors
- Operating Input Voltage Range: 1.6 V to 5.5 V
- Available in Fixed Voltage Options: 1.5 V to 5 V
Contact Factory for Other Voltage Options
- $\pm 1\%$ Typical Accuracy @ 25°C
- Very Low Quiescent Current of Typ. 45 μA
- Standby Current: 0.1 μA
- Very Low Dropout: 125 mV for 3.3 V @ 150 mA
- High PSRR: 55 dB @ 1 kHz
- Available in
 - XDFN4 – 0.8 mm x 0.8 mm x 0.4 mm Package
 - XDFN4 – 1.0 mm x 1.0 mm x 0.4 mm Package
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Battery-powered Equipment
- Smartphones, Tablets
- Cameras, DVRs, STB and Camcorders

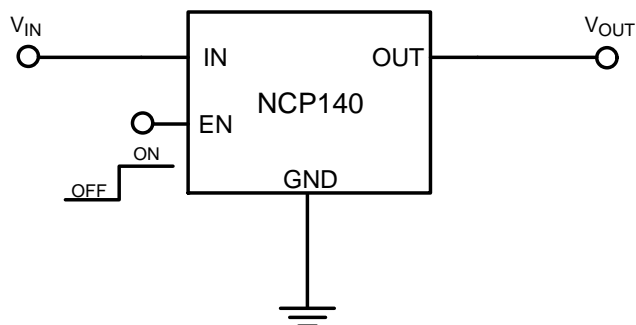


Figure 1. Typical Application Schematic



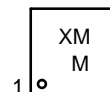
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MARKING DIAGRAMS



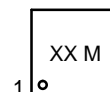
XDFN4, 0.8x0.8
CASE 711BF
(In development)



X = Specific Device Code
MM = Date Code

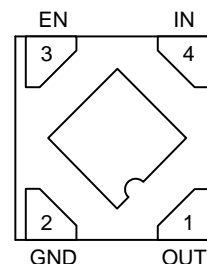


XDFN4, 1.0x1.0
CASE 711AJ



XX = Specific Device Code
M = Date Code

PIN CONNECTIONS

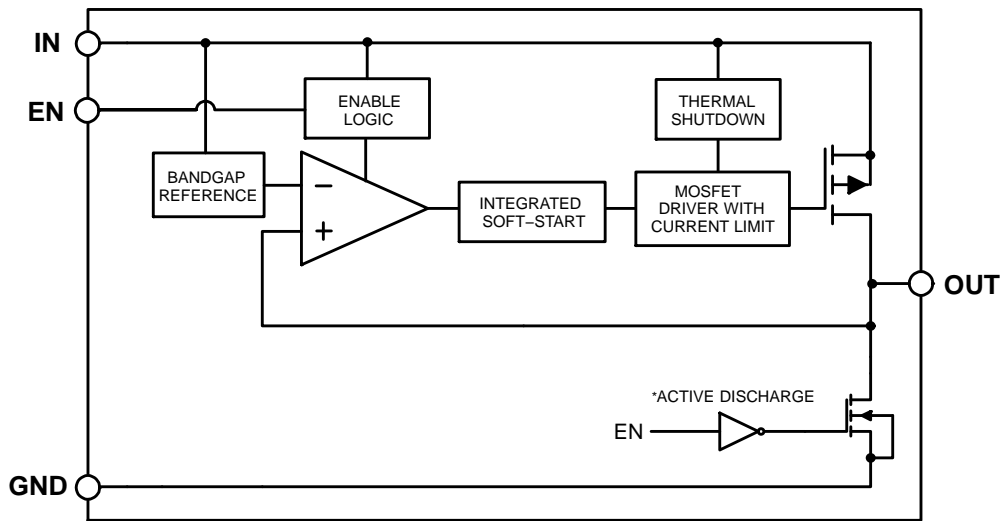


(Bottom View)

ORDERING INFORMATION

See detailed ordering and shipping information on page 3 of this data sheet.

NCP140



*Active output discharge is available only for NCP140Axxx options.

Figure 2. Simplified Schematic Block Diagram

PIN FUNCTION DESCRIPTION

Pin No.	Pin Name	Description
1	OUT	Regulated output voltage pin. A small ceramic capacitor can be connected to improve fast load transient.
2	GND	Ground pin
3	EN	Driving EN over 0.9 V turns on the regulator. Driving EN below 0.4 V puts the regulator into shutdown mode.
4	IN	Input pin
-	EPAD	Expose pad must be connect to GND pin as short as possible. Soldered to a large ground copper plane allows for effective heat removal.

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	V_{IN}	-0.3 V to 6	V
Output Voltage	V_{OUT}	-0.3 V to $V_{IN} + 0.3$ V or 6 V	V
Chip Enable Input	V_{CE}	-0.3 V to $V_{IN} + 0.3$ V or 6 V	V
Output Short Circuit Duration	t_{SC}	unlimited	s
Maximum Junction Temperature	T_J	150	°C
Storage Temperature	T_{STG}	-55 to 150	°C
ESD Capability, Human Body Model (Note 2)	ESD_{HBM}	2000	V
ESD Capability, Machine Model (Note 2)	ESD_{MM}	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

2. This device series incorporates ESD protection and is tested by the following methods:

ESD Human Body Model tested per EIA/JESD22-A114

ESD Machine Model tested per EIA/JESD22-A115

Latchup Current Maximum Rating tested per JEDEC standard: JESD78.

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, XDFN4 0.8 mm x 0.8 mm Thermal Resistance, Junction-to-Air	$R_{\theta JA}$	TBD	°C/W
Thermal Characteristics, XDFN4 1.0 mm x 1.0 mm Thermal Resistance, Junction-to-Air	$R_{\theta JA}$	250	°C/W

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ELECTRICAL CHARACTERISTICS $-40^{\circ}\text{C} \leq T_J \leq 85^{\circ}\text{C}$; $V_{IN} = V_{OUT(NOM)} + 0.5\text{ V}$; $I_{OUT} = 1\text{ mA}$, $C_{IN} = C_{OUT} = \text{none}$, unless otherwise noted. $V_{EN} = 0.9\text{ V}$. Typical values are at $T_J = +25^{\circ}\text{C}$. Min/Max values are for $-40^{\circ}\text{C} \leq T_J \leq 85^{\circ}\text{C}$ (Note 3)

Parameter	Test Conditions	Symbol	Min	Typ.	Max	Unit	
Operating Input Voltage		V_{IN}	1.6		5.5	V	
Output Voltage Accuracy	$V_{OUT} \geq 1.8\text{ V}$, $T_J = 25^{\circ}\text{C}$	V_{OUT}		± 1		%	
	$V_{OUT} < 1.8\text{ V}$, $T_J = 25^{\circ}\text{C}$			± 20		mV	
	$V_{OUT} \geq 1.8\text{ V}$, $-40^{\circ}\text{C} \leq T_J \leq 85^{\circ}\text{C}$		-2		+2	%	
	$V_{OUT} < 1.8\text{ V}$, $-40^{\circ}\text{C} \leq T_J \leq 85^{\circ}\text{C}$		-50		+50	mV	
Line Regulation	$V_{OUT(NOM)} + 0.5\text{ V} \leq V_{IN} \leq 5.5\text{ V}$	LineReg		1.0	5.0	mV	
Load Regulation	$I_{OUT} = 0\text{ mA to } 150\text{ mA}$	LoadReg		10	30	mV	
Dropout Voltage (Note 4)	$I_{OUT} = 150\text{ mA}$	$V_{OUT(NOM)} = 1.8\text{ V}$	V_{DO}		255	280	mV
		$V_{OUT(NOM)} = 3.3\text{ V}$			125	145	
Output Current Limit	$V_{OUT} = 90\% V_{OUT(NOM)}$	I_{CL}		230		mA	
Short Circuit Current	$V_{OUT} = 0\text{ V}$	I_{SC}		250		mA	
Quiescent Current	$I_{OUT} = 0\text{ mA}$	I_Q		45	75	μA	
Shutdown Current	$V_{EN} \leq 0.4\text{ V}$, $V_{IN} = 5.5\text{ V}$	I_{DIS}		0.1	1.0	μA	
EN Pin Threshold Voltage	EN Input Voltage "H"	V_{ENH}	0.9			V	
	EN Input Voltage "L"	V_{ENL}			0.4		
EN Pin Current	$V_{EN} = 5.5\text{ V}$	I_{EN}		0.01	1.0	μA	
Turn-On Time	$C_{OUT} = 1\text{ }\mu\text{F}$, $I_{OUT} = 150\text{ mA}$, From assertion of V_{EN} to $V_{OUT} = 98\% V_{OUT(NOM)}$	T_{ON}		100		μs	
Power Supply Rejection Ratio	$V_{IN} = 3.5\text{ V}$, $V_{OUT(NOM)} = 2.5\text{ V}$, $I_{OUT} = 10\text{ mA}$	$f = 100\text{ Hz}$	PSRR		62	dB	
		$f = 1\text{ kHz}$			55		
Output Noise Voltage	$V_{IN} = 2.3\text{ V}$, $V_{OUT(NOM)} = 1.8\text{ V}$, $I_{OUT} = 10\text{ mA}$ $f = 100\text{ Hz to } 100\text{ kHz}$	V_N		17		μV_{RMS}	
Thermal Shutdown Temperature	Temperature increasing from $T_J = +25^{\circ}\text{C}$	T_{SD}		160		$^{\circ}\text{C}$	
Thermal Shutdown Hysteresis	Temperature falling from T_{SD}	T_{SDH}		20		$^{\circ}\text{C}$	
Output Discharge Pull-Down	$V_{EN} \leq 0.4\text{ V}$, A options only	R_{DISCH}		100		Ω	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Performance guaranteed over the indicated operating temperature range by design and/or characterization. Production tested at $T_A = 25^{\circ}\text{C}$. Low duty cycle pulse techniques are used during the testing to maintain the junction temperature as close to ambient as possible.
4. Dropout voltage is characterized when V_{OUT} falls 100 mV below $V_{OUT(NOM)}$.

ORDERING INFORMATION

Device	Nominal Output Voltage	Description	Marking	Package	Shipping [†]
NCP140AMXC180TCG	1.8 V	Active Output Discharge	GA	XDFN4 (Pb-Free) CASE 711BF	3000 / Tape & Reel (Available soon)
NCP140AMXC280TCG	2.8 V		GC		
NCP140AMXC300TCG	3.0 V		GE		
NCP140AMXC330TCG	3.3 V		GD		
NCP140BMXC330TCG	3.3 V	Without Active Output Discharge	G2		
NCP140AMXD180TCG	1.8 V	Active Output Discharge	GA	XDFN4 (Pb-Free) CASE 711AJ	3000 / Tape & Reel
NCP140AMXD280TCG	2.8 V		GC		
NCP140AMXD300TCG	3.0 V		GE		
NCP140AMXD330TCG	3.3 V		GD		
NCP140BMXD330TCG	3.3 V	Without Active Output Discharge	G2		

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL CHARACTERISTICS

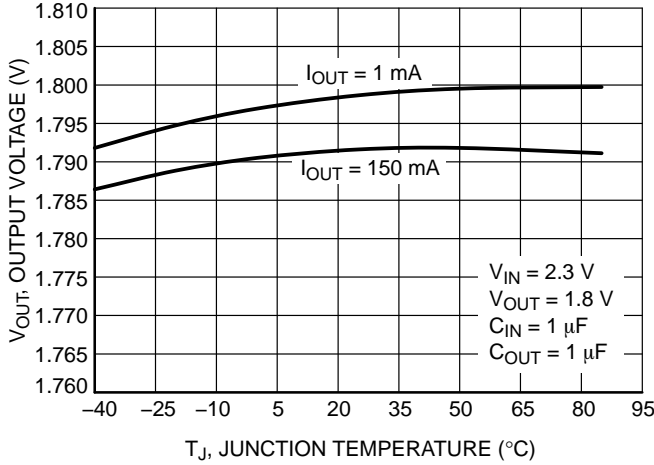


Figure 3. Output Voltage vs. Temperature

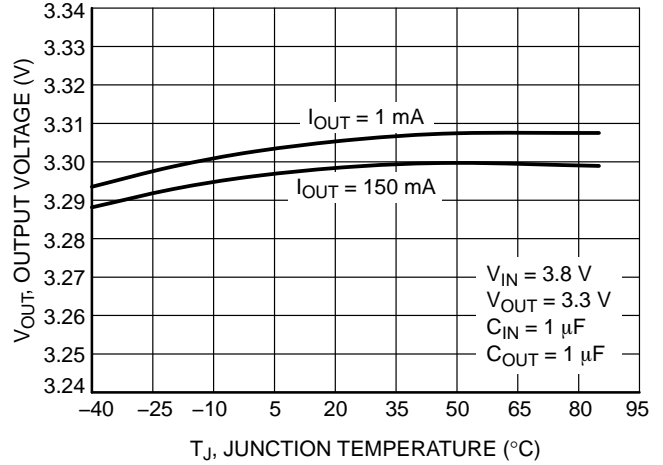


Figure 4. Output Voltage vs. Temperature

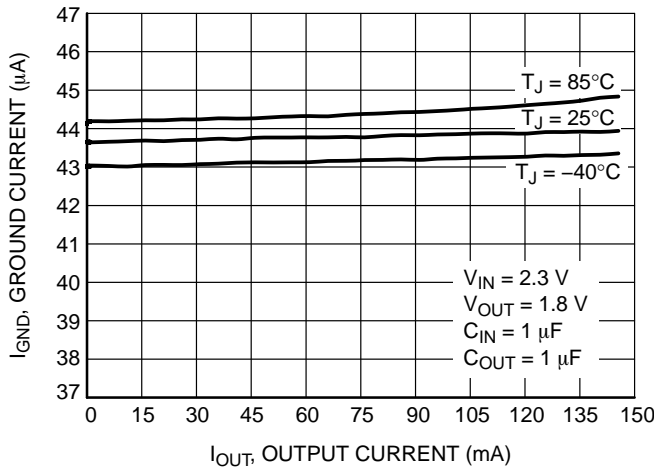


Figure 5. Ground Current vs. Output Current

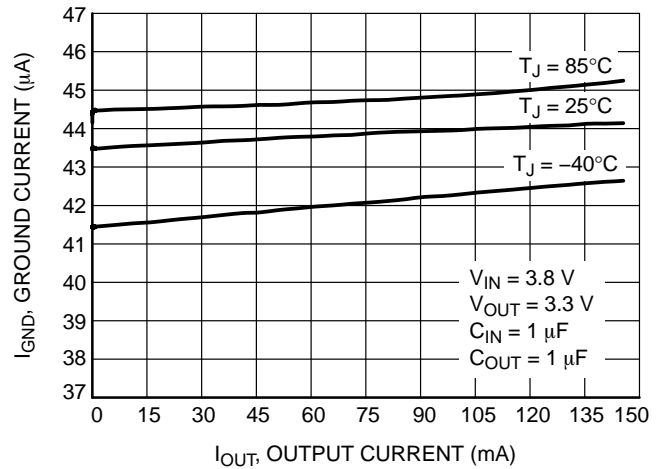


Figure 6. Ground Current vs. Output Current

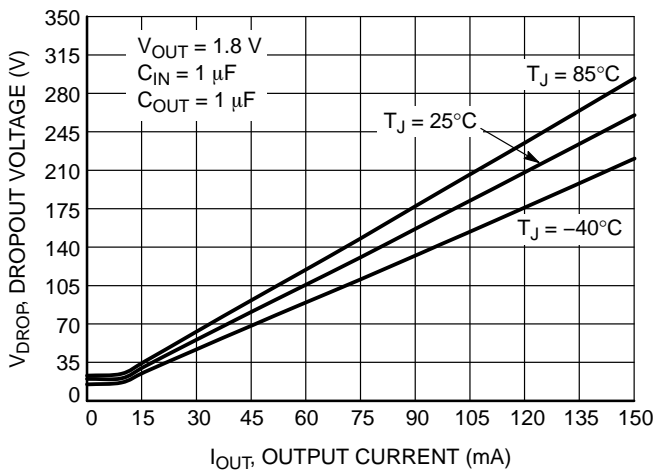


Figure 7. Dropout Voltage vs. Output Current

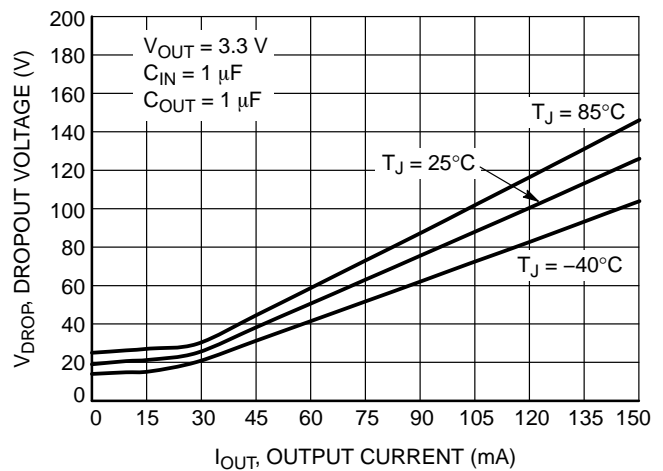


Figure 8. Dropout Voltage vs. Output Current

APPLICATIONS INFORMATION

General

The NCP140 is high performance low dropout regulator capable of supplying 150 mA and providing very stable output voltage with or without capacitors. The device is designed to remain stable with any type of capacitor or even without input and output capacitor. The NCP140 also offers low quiescent current and very small packages suitable for space constrained application. In connection with no capacitor requirements the regulator is very useful in wearable application, smartphones and everywhere where is high power density required.

Input and Output Capacitor Selection

In spite of the NCP140 is designed as capless device capacitors can be added to improve dynamic behavior such as fast load transient or PSRR. Recommendation for selection input and output capacitor is very similar as for high performance LDO. Low ESR ceramic capacitor is the most beneficial for improvement load transient and PSRR but suitable is almost any type of capacitor. The NCP140 remains stable with electrolytic and tantalum capacitor too.

Enable Operation

The NCP140 uses the EN pin to enable/disable its device and to deactivate/activate the active discharge function.

If the EN pin voltage is <0.4 V the device is guaranteed to be disabled. The pass transistor is turned-off so that there is virtually no current flow between the IN and OUT. The active discharge transistor is active (only A option) so that the output voltage V_{OUT} is pulled to GND through a 100 Ω resistor. In the disable state the device consumes as low as typ. 10 nA from the V_{IN} .

If the EN pin voltage >0.9 V the device is guaranteed to be enabled. The NCP140 regulates the output voltage and the active discharge transistor is turned-off.

The EN pin has internal pull-down current source with typ. value of 100 nA which assures that the device is turned-off when the EN pin is not connected. In the case where the EN function isn't required the EN should be tied directly to IN.

Output Current Limit

Output Current is internally limited within the IC to a typical 230 mA. The NCP140 will source this amount of current measured with a voltage drops on the 90% of the nominal V_{OUT} . If the Output Voltage is directly shorted to ground ($V_{OUT} = 0$ V), the short circuit protection will limit the output current to approximately 250 mA. The current limit and short circuit protection will work properly over whole temperature range and also input voltage range. There is no limitation for the short circuit duration.

Thermal Shutdown

When the die temperature exceeds the Thermal Shutdown threshold ($T_{SD} - 160^{\circ}\text{C}$ typical), Thermal Shutdown event is detected and the device is disabled. The IC will remain in this state until the die temperature decreases below the Thermal Shutdown Reset threshold ($T_{SDU} - 140^{\circ}\text{C}$ typical). Once the IC temperature falls below the 140°C the LDO is enabled again. The thermal shutdown feature provides the protection from a catastrophic device failure due to accidental overheating. This protection is not intended to be used as a substitute for proper heat sinking.

Power Dissipation

As power dissipated in the NCP140 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part.

The maximum power dissipation the NCP140 can handle is given by:

$$P_{D(\text{MAX})} = \frac{[85^{\circ}\text{C} - T_A]}{\theta_{JA}} \quad (\text{eq. 1})$$

The power dissipated by the NCP140 for given application conditions can be calculated from the following equation:

$$P_D \approx V_{IN}(I_{\text{GND}}@I_{\text{OUT}}) + I_{\text{OUT}}(V_{IN} - V_{\text{OUT}}) \quad (\text{eq. 2})$$

Reverse Current

The PMOS pass transistor has an inherent body diode which will be forward biased in the case that $V_{OUT} > V_{IN}$. Due to this fact in cases, where the extended reverse current condition can be anticipated the device may require additional external protection.

Turn-On Time

The turn-on time is defined as the time period from EN assertion to the point in which V_{OUT} will reach 98% of its nominal value. This time is dependent on various application conditions such as $V_{\text{OUT}(\text{NOM})}$, C_{OUT} , T_A .

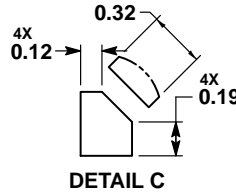
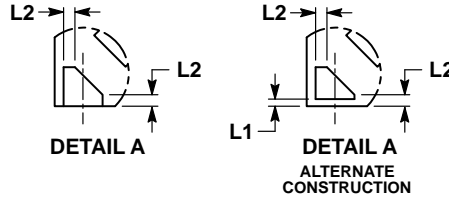
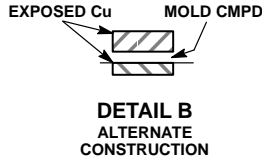
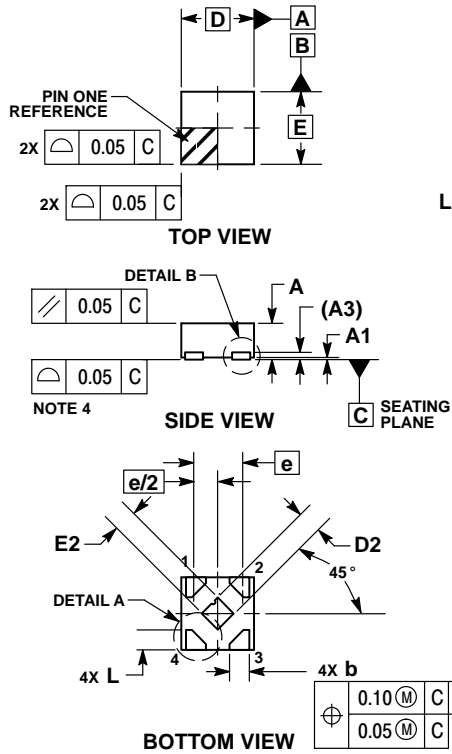
PCB Layout Recommendations

Larger copper area connected to the pins will improve the device thermal resistance and improve maximum power dissipation. The actual power dissipation can be calculated from the equation above (Equation 2). Expose pad should be tied the shortest path to the GND pin.

NCP140

PACKAGE DIMENSIONS

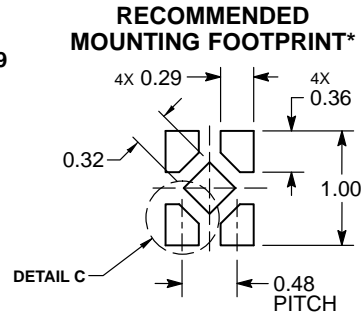
XDFN4 0.8x0.8, 0.48P
CASE 711BF
ISSUE O



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINALS.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

MILLIMETERS		
DIM	MIN	MAX
A	0.33	0.43
A1	0.00	0.05
A3	0.127	REF
b	0.17	0.27
D	0.80	BSC
D2	0.20	0.30
E	0.80	BSC
E2	0.20	0.30
e	0.48	BSC
L	0.17	0.27
L1	—	0.10
L2	—	0.06 REF



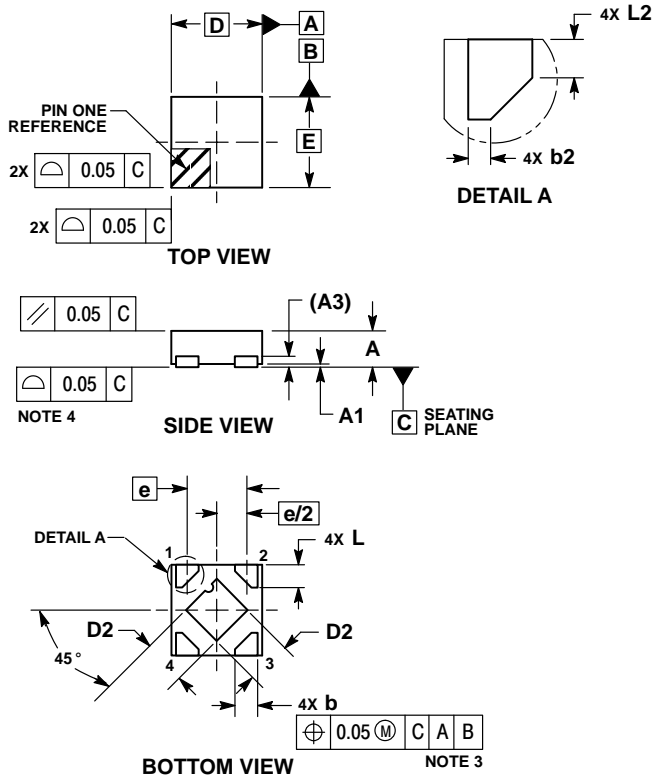
DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NCP140

PACKAGE DIMENSIONS

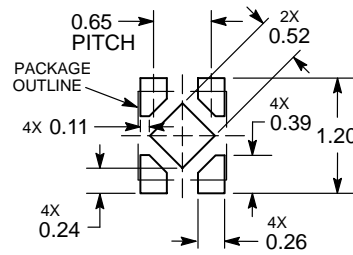
XDFN4 1.0x1.0, 0.65P
CASE 711AJ
ISSUE A



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 mm FROM THE TERMINAL TIPS.
 4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

MILLIMETERS		
DIM	MIN	MAX
A	0.33	0.43
A1	0.00	0.05
A3	0.10 REF	
b	0.15	0.25
b2	0.02	0.12
D	1.00 BSC	
D2	0.43	0.53
E	1.00 BSC	
e	0.65 BSC	
L	0.20	0.30
L2	0.07	0.17

RECOMMENDED MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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